

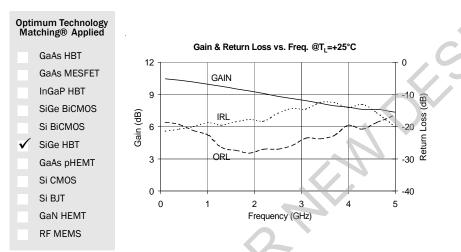
DC to 5000 MHz, CASCADABLE SiGe HBT MMIC AMPLIFIER





### **Product Description**

The SGA2186Z is a high performance SiGe HBT MMIC Amplifier. A Darlington configuration featuring one-micron emitters provides high  $F_{\rm T}$  and excellent thermal performance. The heterojunction increases breakdown voltage and minimizes leakage current between junctions. Cancellation of emitter junction non-linearities results in higher suppression of intermodulation products. Only two DC-blocking capacitors, a bias resistor, and an optional RF choke are required for operation.



#### Features

- Broadband Operation: DC to 5000MHz
- Cascadable 50Ω
- Operates from Single Supply
- Low Thermal Resistance Package

### Applications

- PA Driver Amplifier
- Cellular, PCS, GSM, UMTS
- IF Amplifier
- Wireless Data, Satellite

<b>B</b> (	Specification					
Parameter	Min.	Тур.	Max.	Unit	Condition	
Small Signal Gain	9.2	10.2	11.2	dB	850MHz	
		9.3		dB	1950MHz	
		8.9		dB	2400MHz	
Output Power at 1dB Compression		7.5		dBm	850MHz	
	Ť	6.7		dBm	1950MHz	
Output Third Intercept Point		20.0		dBm	850MHz	
		19.6		dBm	1950MHz	
Bandwidth Determined by Return Loss		5000		MHz	>10dB	
Input Return Loss		18.2		dB	1950MHz	
Output Return Loss		27.2		dB	1950MHz	
Noise Figure		4.4		dB	1950MHz	
Device Operating Voltage	1.9	2.2	2.5	V		
Device Operating Current	17	20	23	mA		
Thermal Resistance		97		°C/W	junction - lead	

Test Conditions:  $V_S = 5V$ ,  $I_D = 20$  mA Typ., OIP<sub>3</sub> Tone Spacing = 1MHz,  $P_{OUT}$  per tone = -10 dBm,  $R_{BIAS} = 140\Omega$ ,  $T_L = 25$  °C,  $Z_S = Z_L = 50\Omega$ 

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#### **Absolute Maximum Ratings**

Parameter	Rating	Unit
Max Device Current (I <sub>D</sub> )	40	mA
Max Device Voltage (V <sub>D</sub> )	4	V
Max RF Input Power	+18	dBm
Max Junction Temp (T <sub>J</sub> )	+150	°C
Operating Temp Range (T <sub>L</sub> )	-40 to +85	°C
Max Storage Temp	+150	°C

Operation of this device beyond any one of these limits may cause permanent dam-age. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one. Bias Conditions should also satisfy the following expression:

 $I_D V_D < (T_J - T_L) / R_{TH}$ , j-l

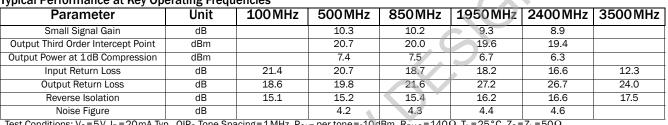
#### Typical Performance at Key Operating Frequencies

Caution! ESD sensitive device.

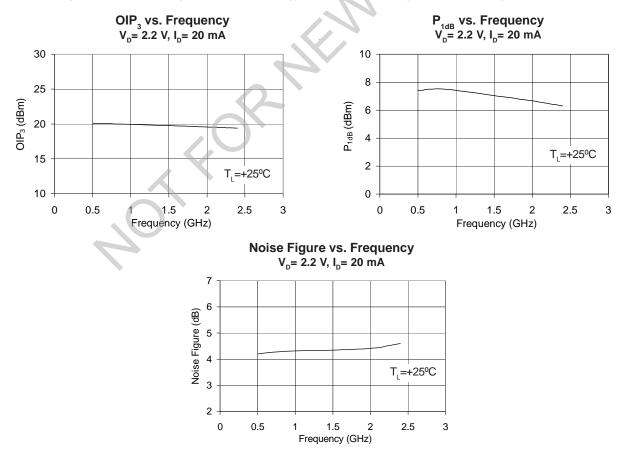
Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical perfor-mance or functional operation of the device under Absolute Maximum Rating condi-tions is not implied.

RoHS status based on EUDirective2002/95/EC (at time of this document revision).

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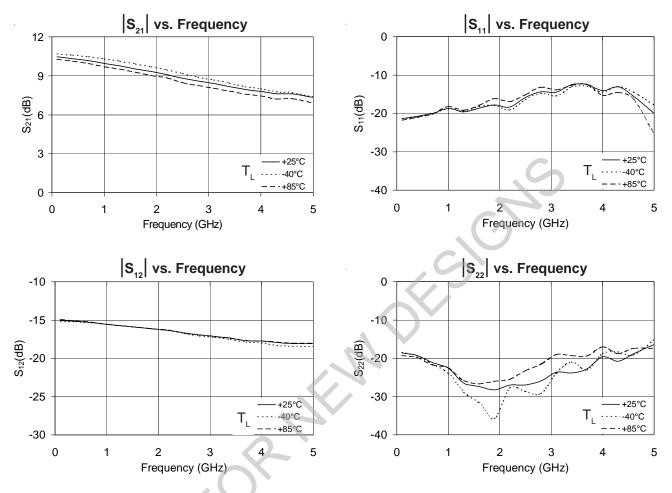


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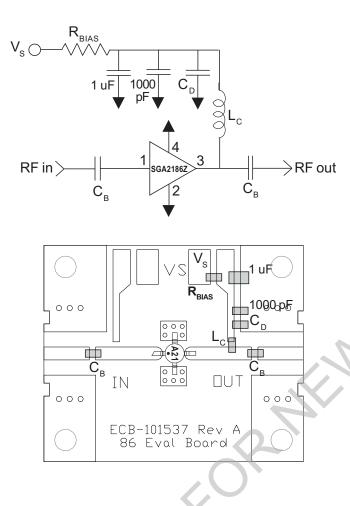
#### Typical RF Performance Over Temperature (Bias: V<sub>D</sub> = 2.2V, I<sub>D</sub> = 20mA (Typ.))



Pin	Function	Description
1	RF IN	RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.
2, 4	GND	Connection to ground. Use via holes for best performance to reduce lead inductance as close to ground leads as possible.
3	RF OUT/BIAS	RF output and bias pin. DC voltage is present on this pin, therefore a DC blocking capacitor is necessary for proper oper- ation.



## **Basic Application Circuit**



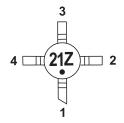
Reference		Frequency (Mhz)				
Designator	500	850	1950	2400	3500	
C <sub>B</sub>	220 pF	100 pF	68 pF	56 pF	39 pF	
C <sub>D</sub>	100 pF	68 pF	22 pF	22 pF	15 pF	
L <sub>c</sub>	68 nH	33 nH	22 nH	18 nH	15 nH	

Recommended Bias Resistor Values for $I_p$ =20mA R <sub>BIAS</sub> =(V <sub>s</sub> -V <sub>b</sub> )/I <sub>b</sub>				
Supply Voltage(V <sub>s</sub> )	5 V	6 V	8 V	10 V
R <sub>BIAS</sub>	140Ω	200 Ω	300 Ω	390 Ω
Note: $R_{\text{BIAS}}$ provides DC bias stability over temperature.				

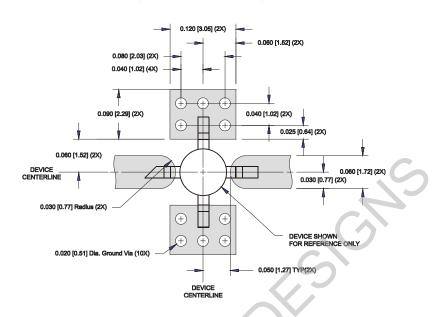
#### **Mounting Instructions**

- 1. Use a large ground pad area under device pins 2 and 4 with many plated through-holes as shown.
- 3. We recommend 1 or 2 ounce copper. Measurements for this data sheet were made on a 31 mil thick FR-4 board with 1 ounce copper on both sides.

### Part Identification Marking



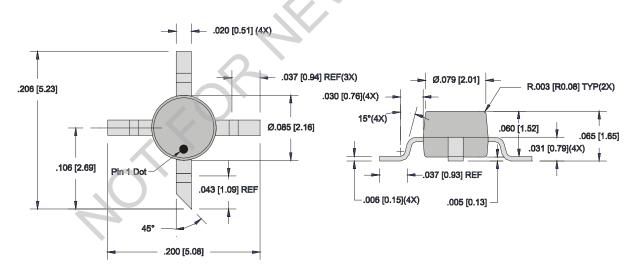




### **Suggested Pad Layout**

### **Package Drawing**

Dimensions in inches (millimeters) Refer to drawing posted at www.rfmd.com for tolerances.



### **Ordering Information**

Ordering Code	Description
SGA2186Z	13" Reel with 3000 pieces
SGA2186ZSQ	Sample bag with 25 pieces
SGA2186ZSR	7" Reel with 100 pieces
SGA2186ZPCK1	850MHz, 5V Operation PCBA with 5-piece sample bag

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Authorized Distributor

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Qorvo: SGA2186Z